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FIG. 1

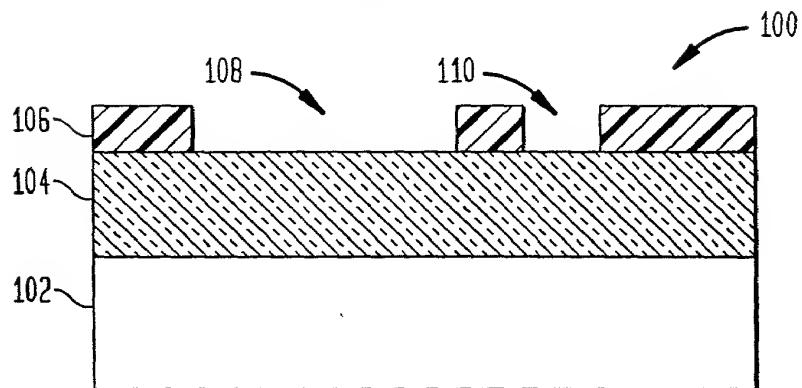


FIG. 2

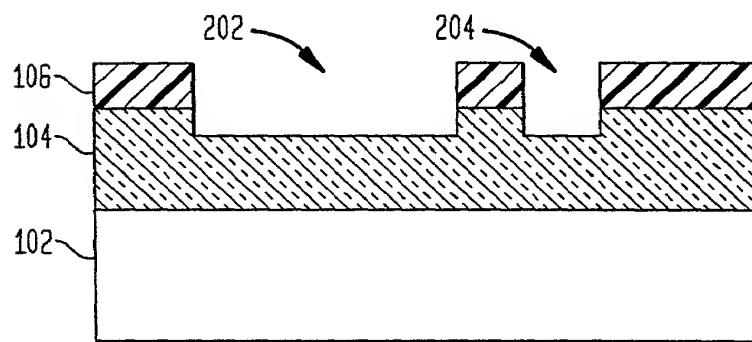
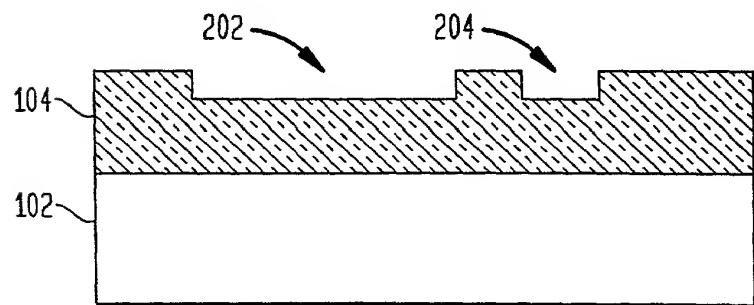


FIG. 3



Appl. No. 09/753,664: Group A11 Unit: 2812
Dkt. No. 1875.0230000, Batch No.: N/A
Inventor(s): Liming Tsau; Tel. 202/371-2600
Title: High Density Metal Capacitor Using Via Etch Stopping
Layer as Field Dielectric in Dual-Damascene

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FIG. 4

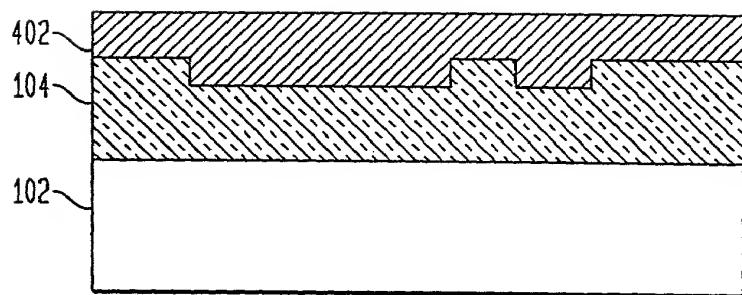


FIG. 5

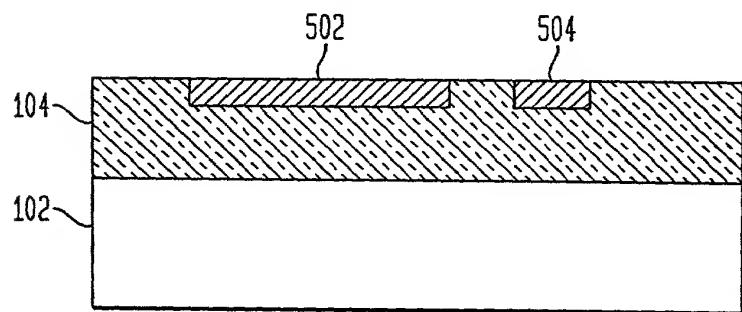
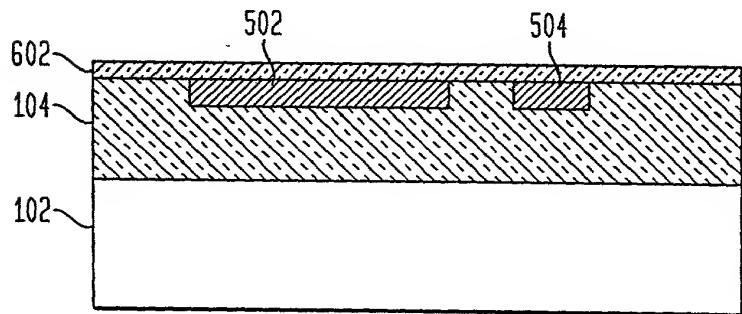


FIG. 6



Appl. No. 09/753,664; Group Art Unit: 2812
Dkt. No. 1875.0230000; Batch No.: N/A
Inventor(s) Liming Tsau; Tel: 202/371-2600
Title. High Density Metal Capacitor Using Via Etch Stopping
Layer as Field Dielectric . . .

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FIG. 7

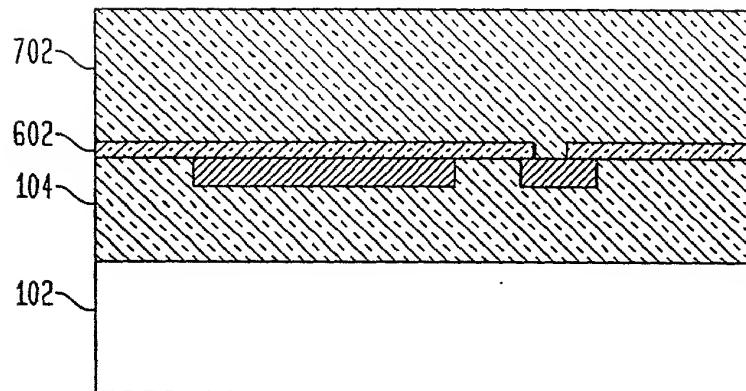


FIG. 8

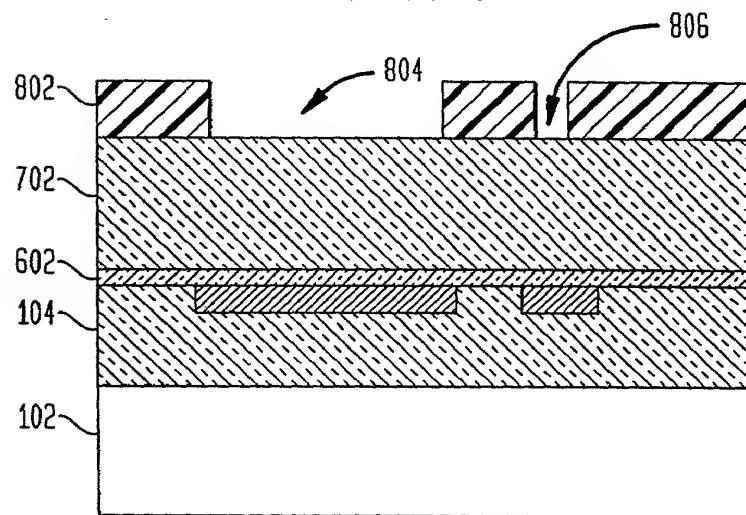
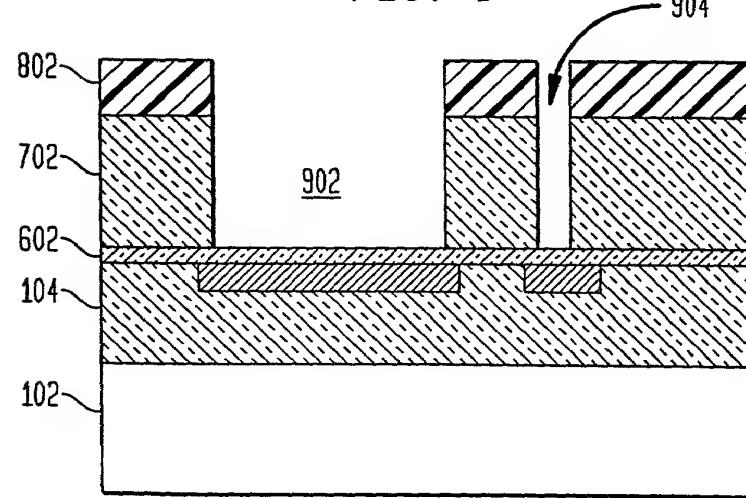


FIG. 9



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FIG. 10

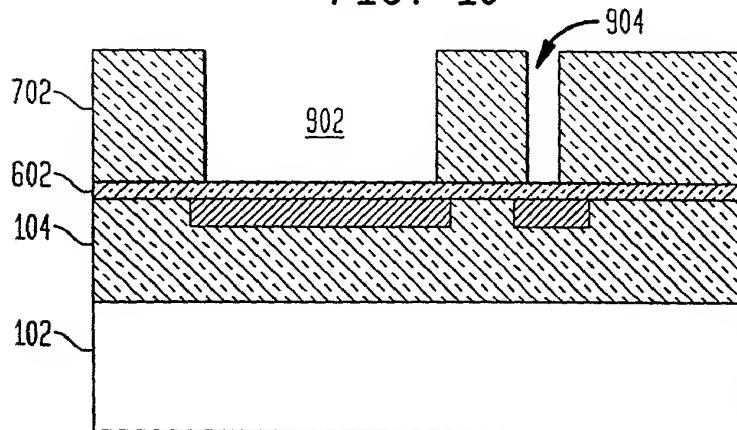


FIG. 11

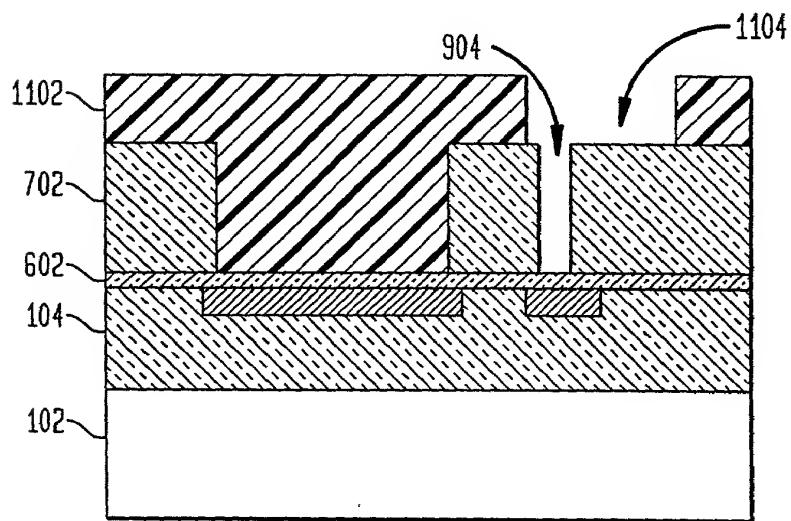
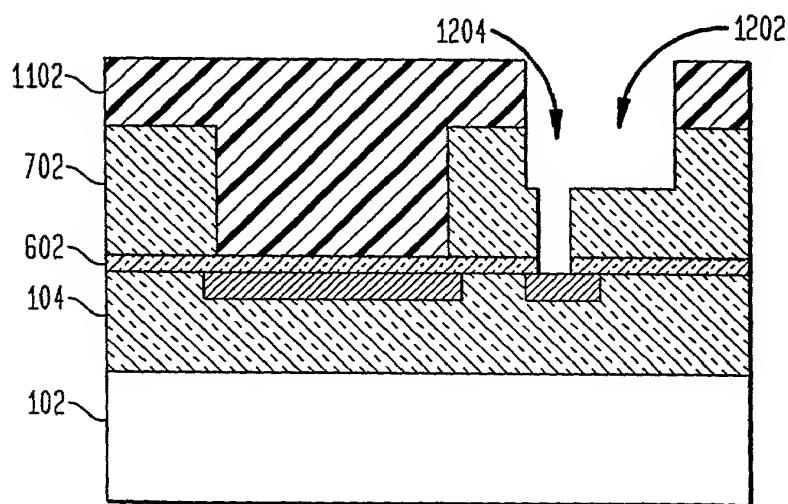


FIG. 12



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FIG. 13

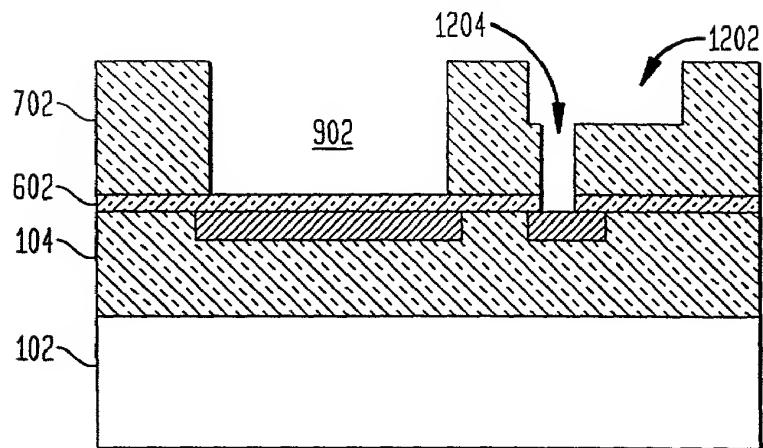


FIG. 14

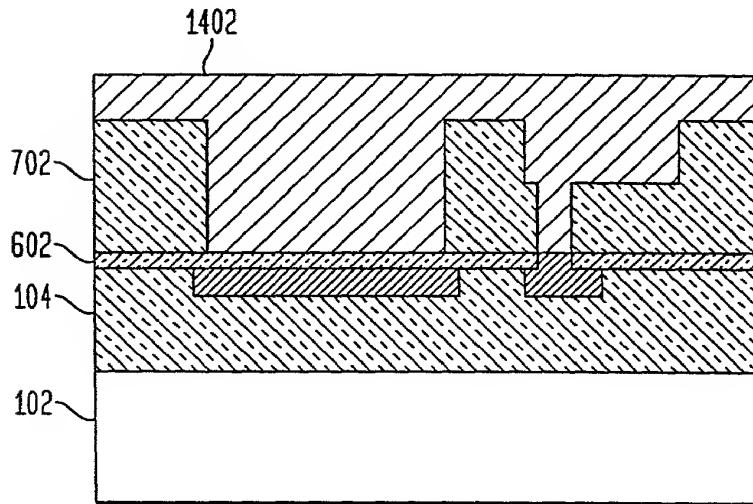


FIG. 15

